High Performance Schottky Rectifier New Generation 3 D-61 Package, 2 x 55 A

Base

common cathode

62

Common

cathode

32 mA at 125 °C

175 °C

Common cathode 15 mJ

3

Anode

2

61 δЗ 52 Anode Common Anode cathode 2 D-61-8-SM Base VS-113CNQ100ASLPbF common cathode 01 3 Anode Anode 2 1 D-61-8-SL **PRODUCT SUMMARY** Package D-61-8, D-61-8-SM, D-61-8-SL 2 x 55 A I_{F(AV)} 100 V V_R 0.81 V V_F at I_F

Anode

1

FEATURES

- 175 °C T_J operation
- · Center tap module
- · Low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- · New fully transfer-mold low profile, small footprint, high current package
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

DESCRIPTION

The center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	110	A			
V _{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	7000	A			
V _F	55 A _{pk} , T _J = 125 °C (per leg)	0.66	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-113CNQ100APbF	UNITS			
Maximum DC reverse voltage	V _R	100	V			
Maximum working peak reverse voltage	V _{RWM}	100	v			

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D-61-8

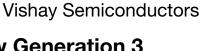
VS-113CNQ100ASMPbF



I_{RM} max. T_J max.

Diode variation

E_{AS}





VS-113CNQ100APbF

ISHA





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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		$I_{F(AV)}$ 50 % duty cycle at T _C = 150 °C, rectangular waveform		55	А	
See fig. 5	per device	I _{F(AV)}	50% duty cycle at $T_{\rm C} = 150\%$ C, rectangular wavelonn		110	~
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	7000	A
			10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	720	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 30 mH		15	mJ
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V _{FM} ⁽¹⁾	55 A	T _{.1} = 25 °C	0.81	V	
Maximum forward voltage drop per leg		110 A	1j=25 C	1.00		
See fig. 1		55 A	T - 105 °C	0.66		
		110 A	T _J = 125 °C	0.79		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	1.0	mA	
See fig. 2		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	32		
Maximum junction capacitance per leg	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1960	pF	
Typical series inductance per leg	Ls	Measured lead to lead 5 mm from package body		5.5	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		D	DC operation See fig. 4	0.5	°C/W	
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	0.25		
Typical thermal resistance, case to heatsink (D-61-8 only)		R _{thCS}	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
Approximate weight				7.8	g	
				0.28	oz.	
Mounting torque minimum			Recommended hardware 3M stainless screw	12 (10)	kgf ⋅ cm	
(D-61-8 only)	maximum		Recommended hardware SWI stainless screw	24 (20)	(lbf · in)	
Marking device			Case style D-61-8	113CNQ100A		
			Case style D-61-8-SM	113CNQ	100ASM	
			Case style D-61-8-SL	113CNQ	100ASL	

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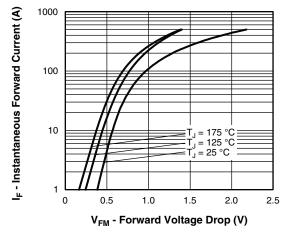
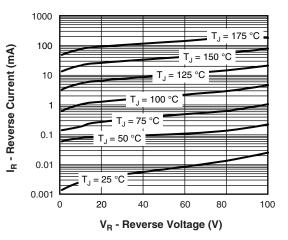
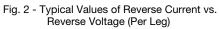


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





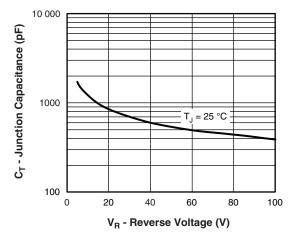
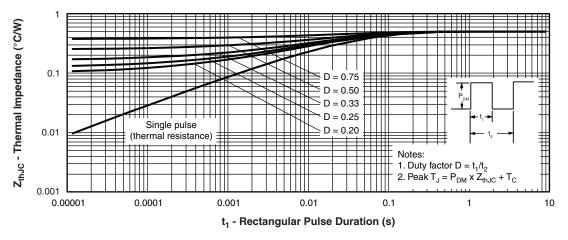
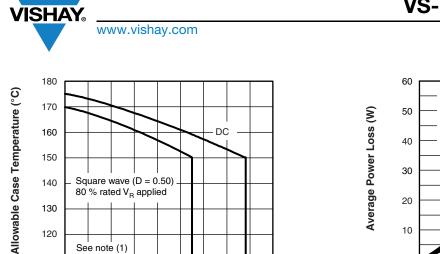


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

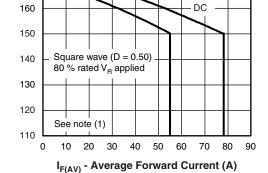


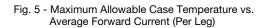


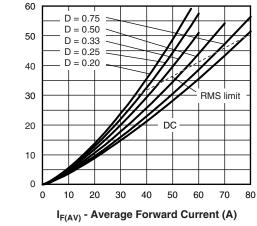
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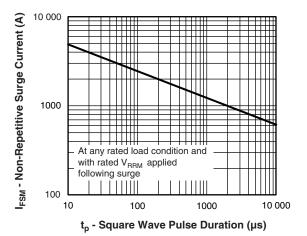


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

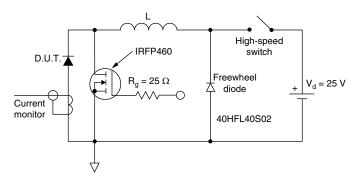


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	113	С	N	Q	100	Α	PbF
	1	2	3	4	5	6	7	8
	1 - 2 - 3 - 3 - 4 - 5 - 6 - 7 -	Curr C = Pac N = Sch Volt Pac • A • AS	rent ratii uit confi commo kage: D-61 ottky "Q age ratii kage sty = D-61-6 SM = D-6	ng (100 /le: 8 61-8-SM 61-8-SL	A) i: de = 100 V	/)	-	
	8 -			andard µ d (Pb)-fr		ion		

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

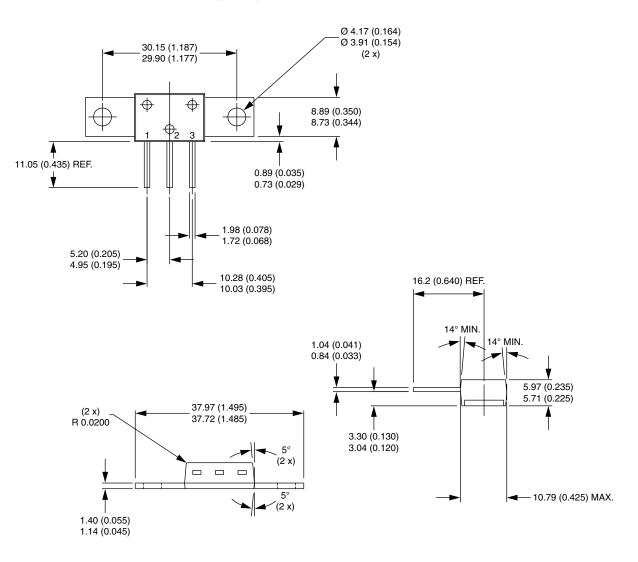
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95354					
Part marking information	www.vishay.com/doc?95356					

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D-61-8, D-61-8-SM, D-61-8-SL

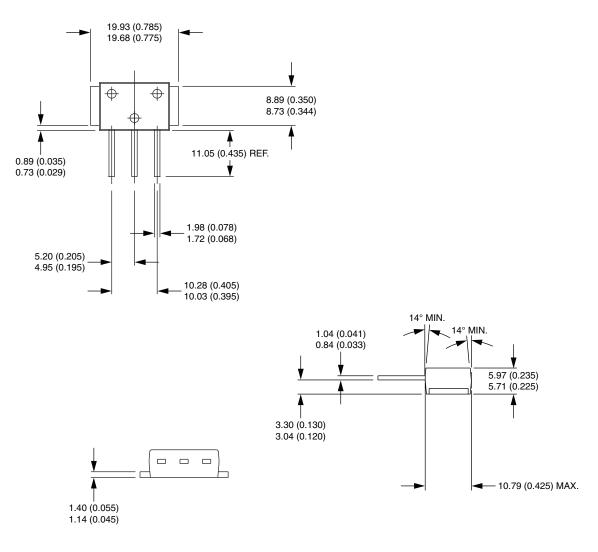
DIMENSIONS - D-61-8 in millimeters (inches)





DIMENSIONS - D-61-8-SM in millimeters (inches)

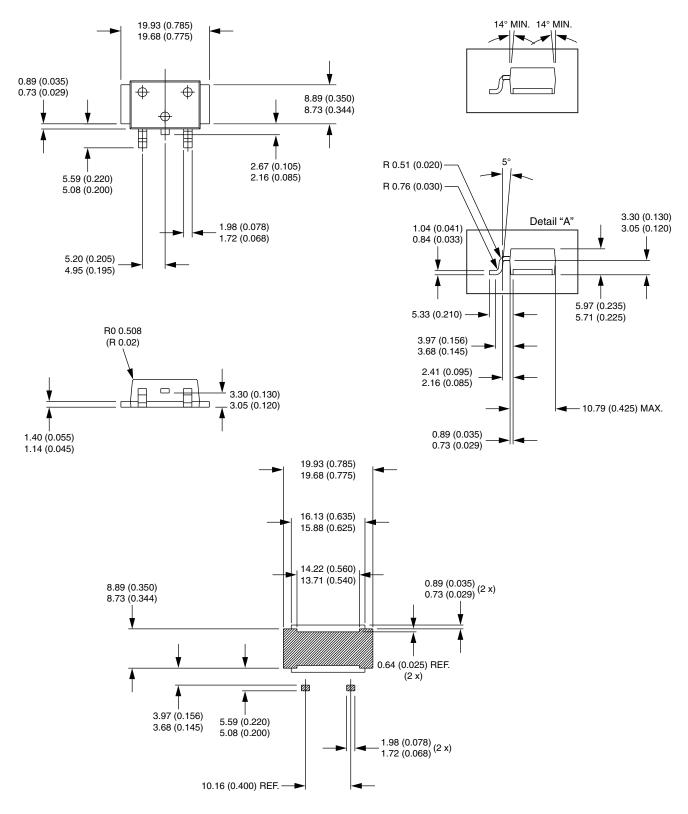
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DIMENSIONS - D-61-8-SL in millimeters (inches)

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